National Semiconductor

CD4027BM/CD4027BC Dual J-K Master/Slave Flip-Flop with Set and Reset

General Description

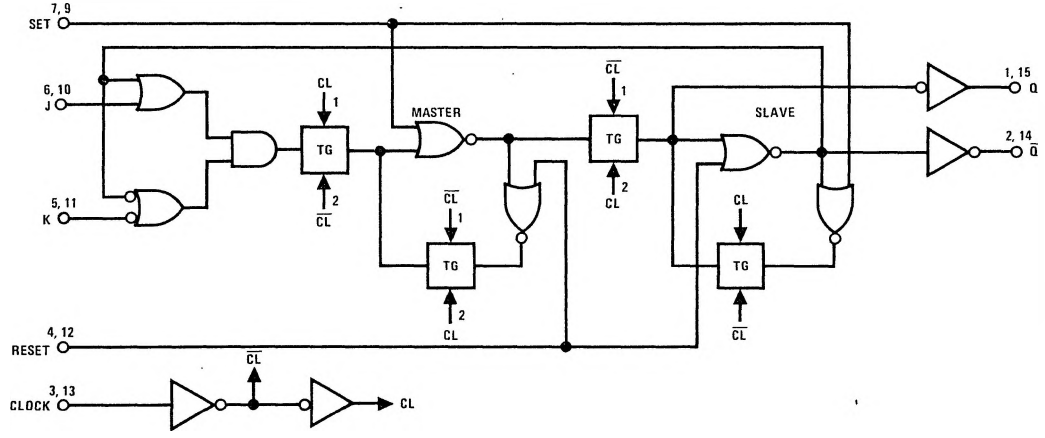
These dual J-K flip-flops are monolithic complementary MOS (CMOS) integrated circuits constructed with N-and P-channel enhancement mode transistors. Each flip-flop has independent J, K, set, reset, and clock inputs and buffered Q and "$\overline{Q}$" outputs. These flip-flops are edge sensitive to the clock input and change state on the positive-going transition of the clock pulses. Set or reset is independent of the clock and is accomplished by a high level on the respective input.

All inputs are protected against damage due to static discharge by diode clamps to V_{DD} and V_{SS}.

Features

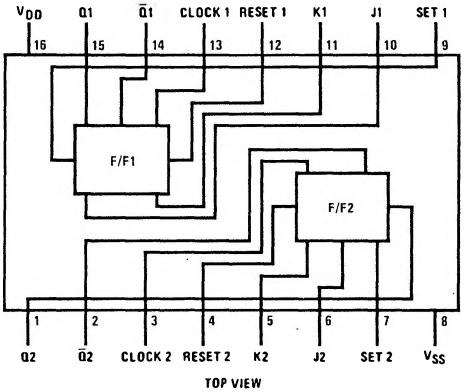
■ Wide supply voltage range	3.0 V to 15 V
■ High noise immunity	0.45 V_{DD} (typ.)
■ Low power TTL compatibility	fan out of 2 driving 74L or 1 driving 74LS
■ Low power	50 nW (typ.)
■ Medium speed operation	12 MHz (typ.) with 10 V supply

Schematic Diagram



Connection Diagram

Dual-In-Line and Flat Package



TOP VIEW

Absolute Maximum Ratings (Notes 1 and 2)

V_{DD} dc Supply Voltage	−0.5 to +18 V_{DC}
V_{IN} Input Voltage	−0.5 to V_{DD} +0.5 V_{DC}
T_S Storage Temperature Range	−65°C to +150°C
P_D Package Dissipation	500 mW
T_L Lead Temperature (Soldering, 10 seconds)	300°C

Recommended Operating Conditions

(Note 2)

V_{DD} dc Supply Voltage	3 to 15 V_{DC}
V_{IN} Input Voltage	0 to V_{DD} V_{DC}
T_A Operating Temperature Range	
CD4027BM	−55°C to +125°C
CD4027BC	−40°C to +85°C

DC Electrical Characteristics CD4027BM (Note 2)

PARAMETER		CONDITIONS	−55°C		25°C			125°C		UNITS
			MIN	MAX	MIN	TYP	MAX	MIN	MAX	
I_{DD}	Quiescent Device Current	V_{DD} = 5V		1			1		30	μA
		V_{DD} = 10V		2			2		60	μA
		V_{DD} = 15V		4			4		120	μA
V_{OL}	Low Level Output Voltage	$\|I_O\| < 1\mu A$								
		V_{DD} = 5V		0.05		0	0.05		0.05	V
		V_{DD} = 10V		0.05		0	0.05		0.05	V
		V_{DD} = 15V		0.05		0	0.05		0.05	V
V_{OH}	High Level Output Voltage	$\|I_O\| < 1\mu A$								
		V_{DD} = 5V	4.95		4.95	5		4.95		V
		V_{DD} = 10V	9.95		9.95	10		9.95		V
		V_{DD} = 15V	14.95		14.95	15		14.95		V
V_{IL}	Low Level Input Voltage	V_{DD} = 5V, V_O = 0.5V or 4.5V		1.5			1.5		1.5	V
		V_{DD} = 10V, V_O = 1V or 9V		3.0			3.0		3.0	V
		V_{DD} = 15V, V_O = 1.5V or 13.5V		4.0			4.0		4.0	V
V_{IH}	High Level Input Voltage	V_{DD} = 5V, V_O = 0.5V or 4.5V	3.5		3.5			3.5		V
		V_{DD} = 10V, V_O = 1V or 9V	7.0		7.0			7.0		V
		V_{DD} = 15V, V_O = 1.5V or 13.5V	11.0		11.0			11.0		V
I_{OL}	Low Level Output Current	V_{DD} = 5V, V_O = 0.4V	0.64		0.51	0.88		0.36		mA
		V_{DD} = 10V, V_O = 0.5V	1.6		1.3	2.25		0.9		mA
		V_{DD} = 15V, V_O = 1.5V	4.2		3.4	8.8		2.4		mA
I_{OH}	High Level Output Current	V_{DD} = 5V, V_O = 4.6V	−0.64		−0.51	−0.88		−0.36		mA
		V_{DD} = 10V, V_O = 9.5V	−1.6		−1.3	−2.25		−0.9		mA
		V_{DD} = 15V, V_O = 13.5V	−4.2		−3.4	−8.8		−2.4		mA
I_{IN}	Input Current	V_{DD} = 15V, V_{IN} = 0V		−0.1		-10^{-5}	−0.1		−1.0	μA
		V_{DD} = 15V, V_{IN} = 15V		0.1		10^{-5}	0.1		1.0	μA

DC Electrical Characteristics (Cont'd.) CD4027BC (Note 2)

PARAMETER		CONDITIONS	−40°C		25°C			85°C		UNITS
			MIN	MAX	MIN	TYP	MAX	MIN	MAX	
I_{DD}	Quiescent Device Current	V_{DD} = 5V		4			4		30	μA
		V_{DD} = 10V		8			8		60	μA
		V_{DD} = 15V		16			16		120	μA
V_{OL}	Low Level Output Voltage	$\|I_O\| < 1\mu A$								
		V_{DD} = 5V		0.05		0	0.05		0.05	V
		V_{DD} = 10V		0.05		0	0.05		0.05	V
		V_{DD} = 15V		0.05		0	0.05		0.05	V
V_{OH}	High Level Output Voltage	$\|I_O\| < 1\mu A$								
		V_{DD} = 5V	4.95		4.95	5		4.95		V
		V_{DD} = 10V	9.95		9.95	10		9.95		V
		V_{DD} = 15V	14.95		14.95	15		14.95		V
V_{IL}	Low Level Input Voltage	V_{DD} = 5V, V_O = 0.5V or 4.5V		1.5			1.5		1.5	V
		V_{DD} = 10V, V_O = 1V or 9V		3.0			3.0		3.0	V
		V_{DD} = 15V, V_O = 1.5V or 13.5V		4.0			4.0		4.0	V
V_{IH}	High Level Input Voltage	V_{DD} = 5V, V_O = 0.5V or 4.5V	3.5		3.5			3.5		V
		V_{DD} = 10V, V_O = 1V or 9V	7.0		7.0			7.0		V
		V_{DD} = 15V, V_O = 1.5V or 13.5V	11.0		11.0			11.0		V
I_{OL}	Low Level Output Current	V_{DD} = 5V, V_O = 0.4V	0.52		0.44	0.88		0.36		mA
		V_{DD} = 10V, V_O = 0.5V	1.3		1.1	2.25		0.9		mA
		V_{DD} = 15V, V_O = 1.5V	3.6		3.0	8.8		2.4		mA

DC Electrical Characteristics CD4027BC (Note 2)

PARAMETER		CONDITIONS	−40°C		25°C			85°C		UNITS
			MIN	MAX	MIN	TYP	MAX	MIN	MAX	
I_{OH}	High Level Output Current	V_{DD} = 5V, V_O = 4.6V	−0.52		−0.44	−0.88		−0.36		mA
		V_{DD} = 10V, V_O = 9.5V	−1.3		−1.1	−2.25		−0.9		mA
		V_{DD} = 15V, V_O = 13.5V	−3.6		−3.0	−8.8		−2.4		mA
I_{IN}	Input Current	V_{DD} = 15V, V_{IN} = 0V		−0.3		-10^{-5}	−0.3		−1.0	μA
		V_{DD} = 15V, V_{IN} = 15V		0.3		10^{-5}	0.3		1.0	μA

AC Electrical Characteristics $T_A = 25°C$, $C_L = 50\,pF$, $t_{rCL} = t_{fCL} = 20\,ns$, unless otherwise specified.

PARAMETER		CONDITIONS	MIN	TYP	MAX	UNITS
t_{PHL} or t_{PLH}	Propagation Delay Time From Clock to Q or $\overline{Q}$	V_{DD} = 5V		200	400	ns
		V_{DD} = 10V		80	160	ns
		V_{DD} = 15V		65	130	ns
t_{PHL} or t_{PLH}	Propagation Delay Time From Set to $\overline{Q}$ or Reset to Q	V_{DD} = 5V		170	340	ns
		V_{DD} = 10V		70	140	ns
		V_{DD} = 15V		55	110	ns
t_{PHL} or t_{PLH}	Propagation Delay Time From Set to Q or Reset to $\overline{Q}$	V_{DD} = 5V		110	220	ns
		V_{DD} = 10V		50	100	ns
		V_{DD} = 15V		40	80	ns
t_s	Minimum Data Set-Up Time	V_{DD} = 5V		135	270	ns
		V_{DD} = 10V		55	110	ns
		V_{DD} = 15V		45	90	ns
t_{THL} or t_{TLH}	Transition Time	V_{DD} = 5V		100	200	ns
		V_{DD} = 10V		50	100	ns
		V_{DD} = 15V		40	80	ns
f_{CL}	Maximum Clock Frequency (Toggle Mode)	V_{DD} = 5V	2.5	5		MHz
		V_{DD} = 10V	6.2	12.5		MHz
		V_{DD} = 15V	7.6	15.5		MHz
t_{rCL} or t_{fCL}	Maximum Clock Rise and Fall Time	V_{DD} = 5V	15			μs
		V_{DD} = 10V	10			μs
		V_{DD} = 15V	5			μs
t_W	Minimum Clock Pulse Width ($t_{WH} = t_{WL}$)	V_{DD} = 5V		100	200	ns
		V_{DD} = 10V		40	80	ns
		V_{DD} = 15V		32	65	ns
t_{WH}	Minimum Set and Reset Pulse Width	V_{DD} = 5V		80	160	ns
		V_{DD} = 10V		30	60	ns
		V_{DD} = 15V		25	50	ns
C_{IN}	Average Input Capacitance	Any Input		5	7.5	pF
C_{PD}	Power Dissipation Capacity	Per Flip-Flop (Note 3)		35		pF

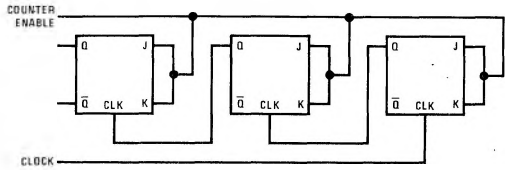
Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The table of "Recommended Operating Conditions" and "Electrical Characteristics" provides conditions for actual device operation.

Note 2: V_{SS} = 0V unless otherwise specified.

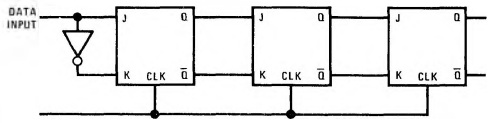
Note 3: C_{PD} determines the no load ac power consumption of any CMOS device. For complete explanation, see 54C/74C Family Characteristics application note AN-90.

Typical Applications

Ripple Binary Counters



Shift Registers



Truth Table

$^{\bullet}t_{n-1}$ INPUTS						$^{\blacklozenge}t_n$ OUTPUTS		
CL▲	J	K	S	R	Q	Q	$\bar{Q}$	
⌐	1	X	0	0	0	1	0	
⌐	X	0	0	0	1	1	0	
⌐	0	X	0	0	0	0	1	
⌐	X	1	0	0	1	0	1	
⌙	X	X	0	0	X			(No change)
X	X	X	1	0	X	1	0	
X	X	X	0	1	X	0	1	
X	X	X	1	1	X	1	1	

Where: 1 = High Level
0 = Low Level
▲ = Level Change
X = Don't Care
● = t_{n-1} refers to the time interval prior to the positive clock pulse transition
◆ = t_n refers to the time intervals after the positive clock pulse transition